

TOSHIBA Transistor Silicon NPN Triple-Diffused Mesa Type

2SD2711

Horizontal Deflection Output for Color TVs

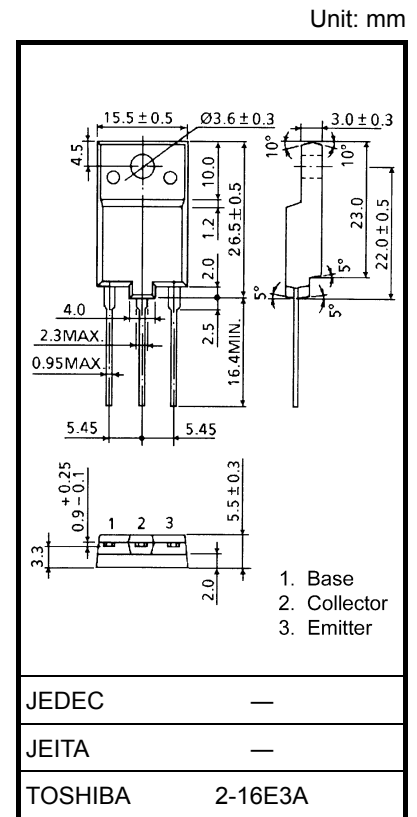
- High voltage : $V_{CBO} = 1700\text{ V}$
- Low saturation voltage : $V_{CE(sat)} = 3\text{ V (max)}$
- Built-in damper type
- Collector metal (fin) is fully covered with mold resin.

Absolute Maximum Ratings ($T_C = 25^\circ\text{C}$)

Characteristic		Symbol	Rating	Unit
Collector-base voltage		V_{CBO}	1700	V
Collector-emitter voltage		V_{CEO}	700	V
Emitter-base voltage		V_{EBO}	7	V
Collector current	DC	I_C	7	A
	Pulse	I_{CP}	14	
Base current		I_B	3.5	A
Collector power dissipation		P_C	50	W
Junction temperature		T_j	150	$^\circ\text{C}$
Storage temperature range		T_{stg}	-55 to 150	$^\circ\text{C}$

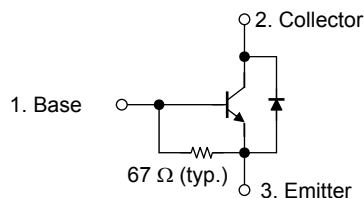
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

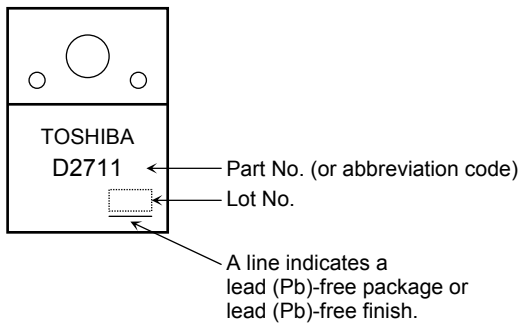


Weight: 5.5 g (typ.)

Equivalent Circuit

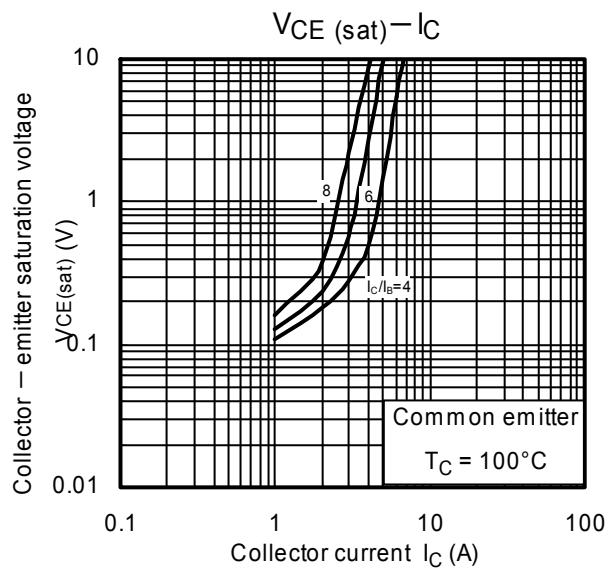
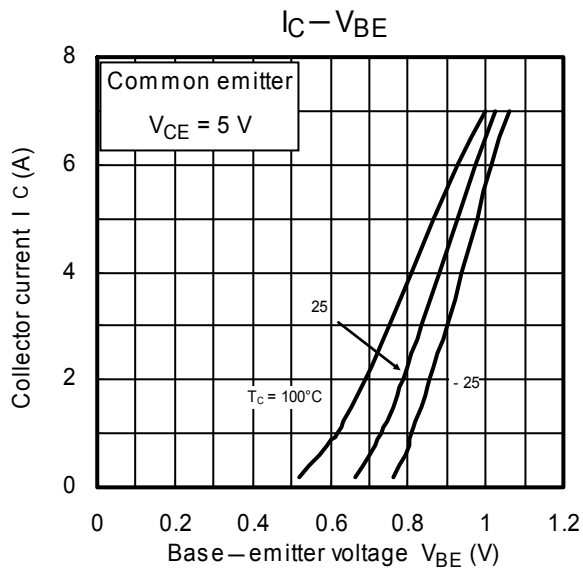
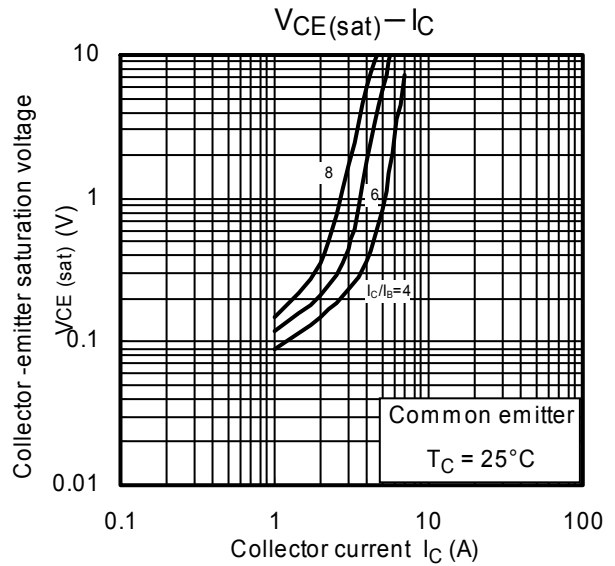
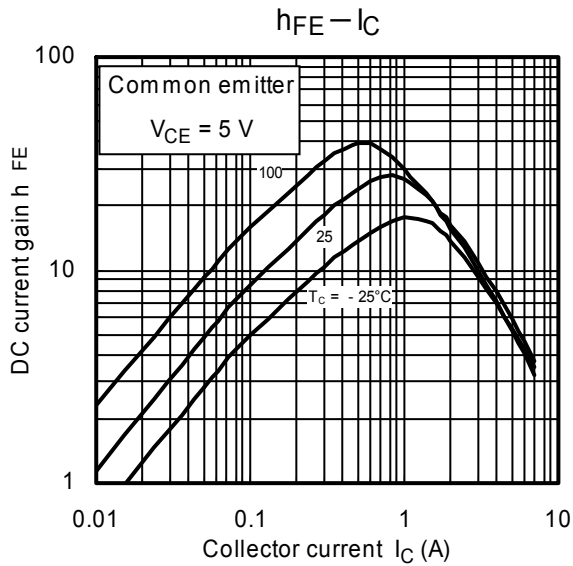
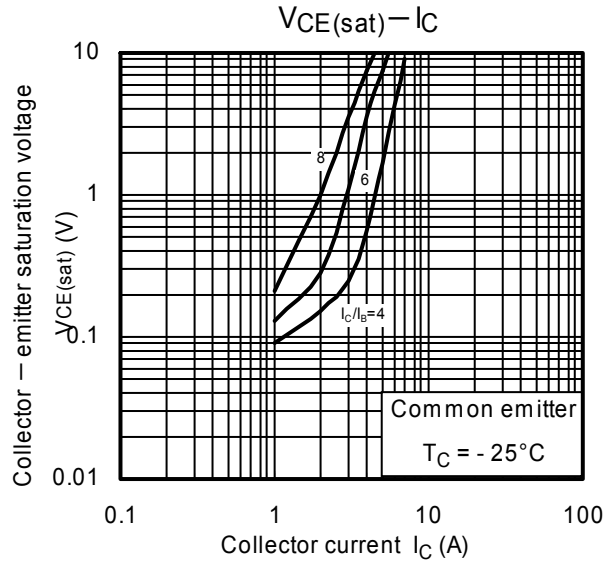
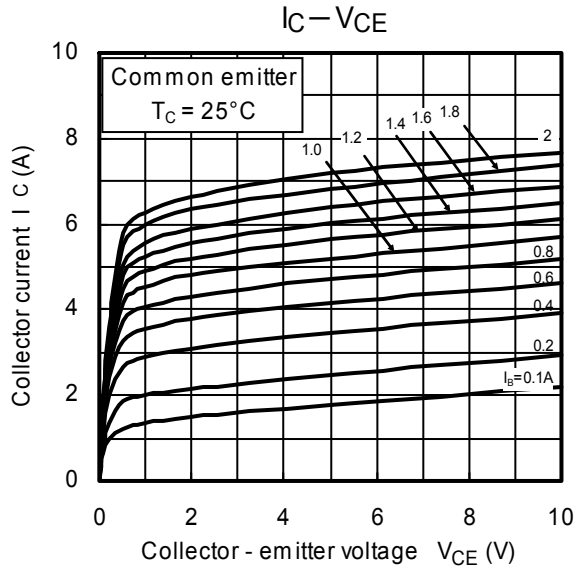


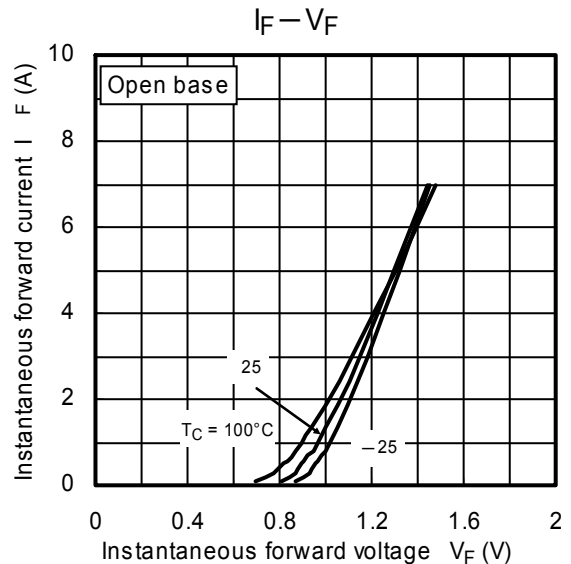
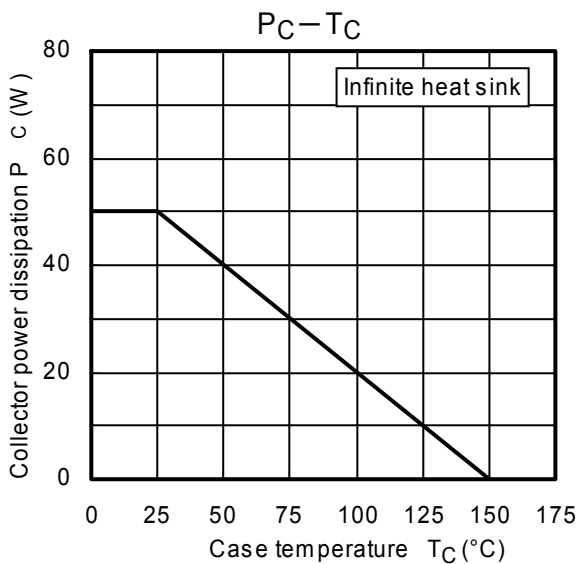
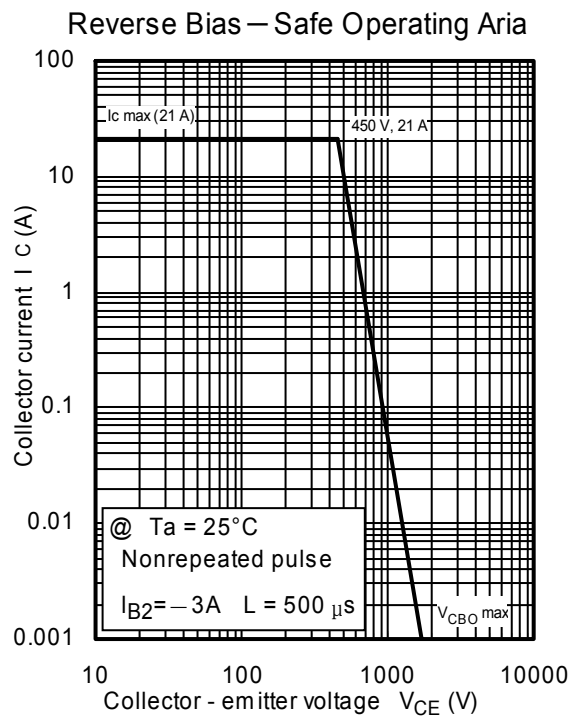
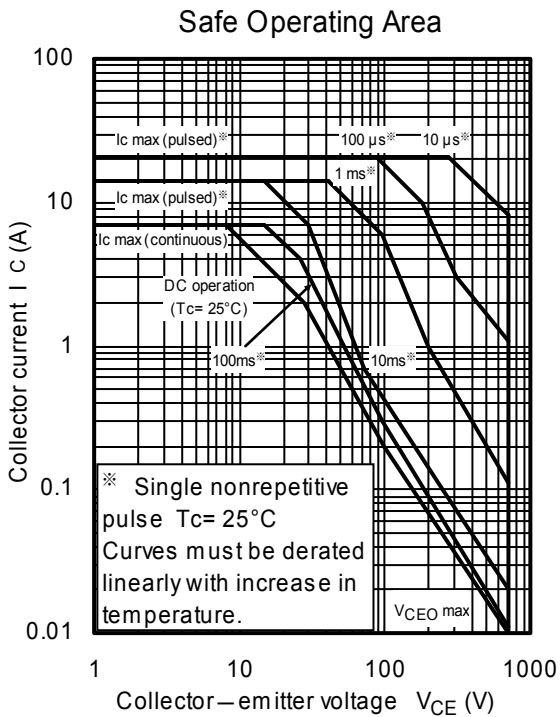
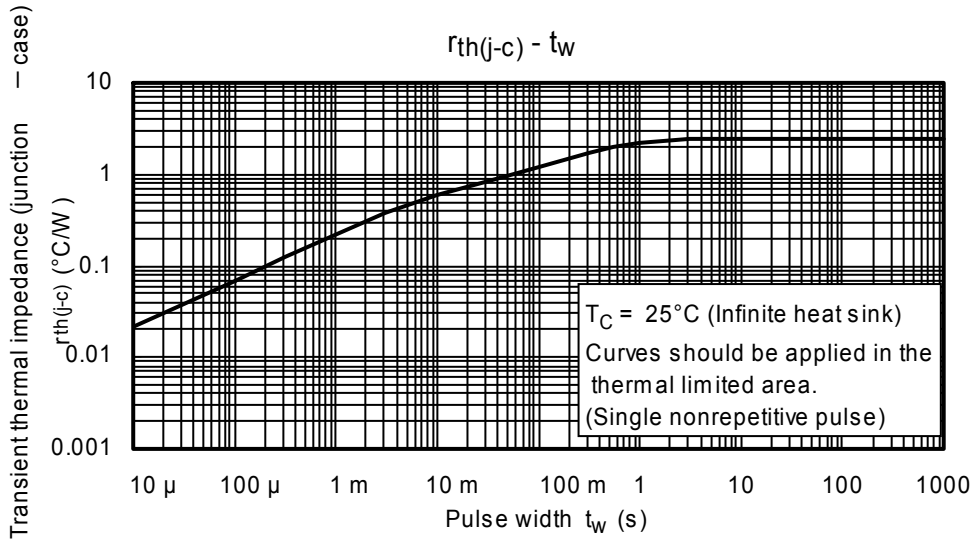
Marking



Electrical Characteristics (T_C = 25°C)

Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cutoff current	I _{CBO}	V _{CB} = 1700 V, I _E = 0	—	—	1	mA
Emitter cutoff current	I _{EBO}	V _{EB} = 5 V, I _C = 0	50	—	100	mA
Emitter–base breakdown voltage	V _{(BR) EBO}	I _E = 500 mA, I _C = 0	7	—	—	V
DC current gain	h _{FE} (1)	V _{CE} = 5 V, I _C = 1 A	20	—	40	—
	h _{FE} (2)	V _{CE} = 5 V, I _C = 5 A	4.7	—	7.5	
Collector–emitter saturation voltage	V _{CE (sat)}	I _C = 5 A, I _B = 1.25 A	—	—	3	V
Base–emitter saturation voltage	V _{BE (sat)}	I _C = 5 A, I _B = 1.25 A	—	—	1.05	V
Forward voltage (damper diode)	V _F	I _F = 5 A	—	—	1.7	V
Transition frequency	f _T	V _{CE} = 10 V, I _C = 0.1 A	—	2	—	MHz
Collector output capacitance	C _{ob}	V _{CB} = 10 V, I _E = 0, f = 1 MHz	—	90	—	pF
Switching time	Storage time	I _{CP} = 5 A, I _{B1} (end) = 1 A f _H = 15.75 kHz	—	7	—	μs
	Fall time		—	0.3	—	





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